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SC91710A/B

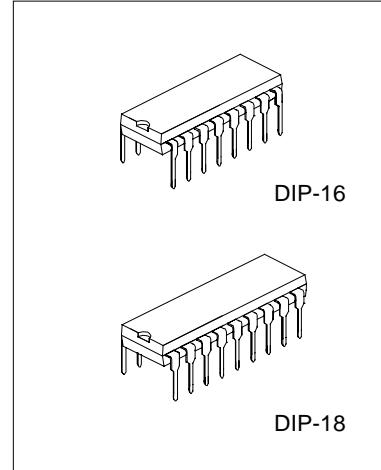
TONE / PULSE SWITCHABLE DIALER WITH HANDFREE FUNCTION

DESCRIPTION

The SC91710A/B are Tone/Pulse switchable dialer which are fabricated in COMS technology with wide operating voltage for both tone and pulse mode, and consumes very low memory retention current in ON-HOOK state.

FEATURES

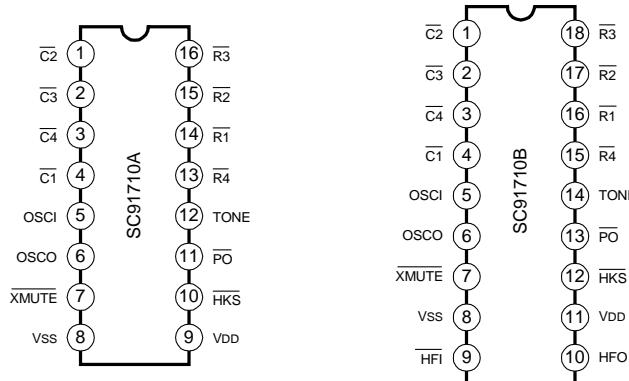
- *Tone/Pulse switchable dialer
- *One 32-digit last number redial memory
- *Pulse-to-tone (P→T) is provided for PBX operation
- *Flash key is available
- *Minimum tone duration is 98ms or 83ms
- *Minimum intertone pause is 98ms or 83ms
- *Redial Pause time (0ms)
- *Uses 3.579549MHz crystal or ceramic resonator
- *Many options can be selected
 - Mode (10PPS; 20PPS; Tone)
 - M/B ratio (40:60;33:66)
 - Pause time (3.6s)
- *Flash function (RESET)
 - (P→T) pause time (3.6s)
 - Flash time (600ms; 300ms; 100ms; or 80ms)
- *Mixed dialing
- *Power on reset circuit is provided
- *Handfree function is provided for speaker phone application
- *Packaged in 16-DIP or 18-DIP



ORDERING INFORMATION

SC91710A	DIP-16 Packaged
SC91710B	DIP-18 Packaged

PIN CONFIGURATION



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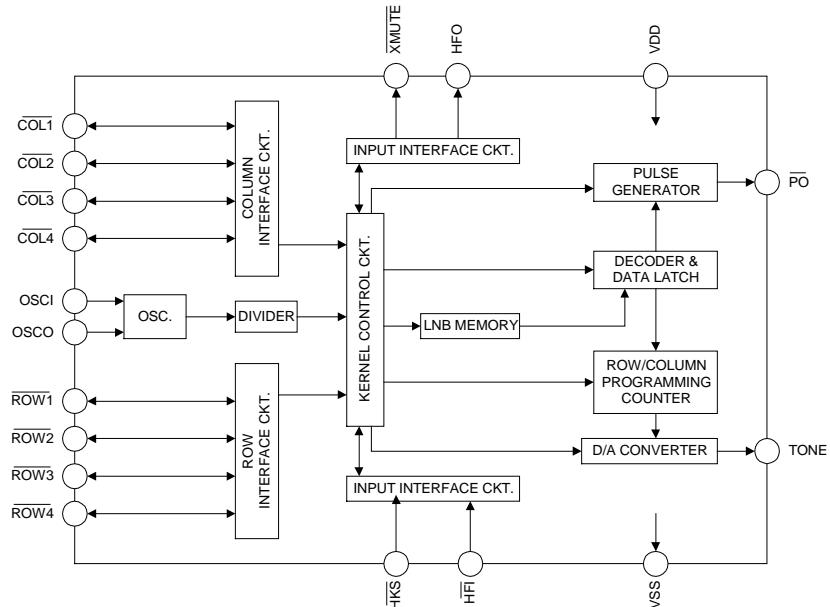
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BLOCK DIAGRAM



KEYBOARD ASSIGNMENT

	C1	C2	C3	C4
R1	1	2	3	P→T
R2	4	5	6	F
R3	7	8	9	P
R4	*or */T	0	#	RD

- 1) P→T: In pulse mode, execute P→T function.
- 2) P: Pause key.
- 3) F: Flash key
- 4) RD: Redial key
- 5) In pulse mode, execute P→T function.
In tone mode, execute "*" key

DIALING SIGNAL OPTION

A: Flash time

Row3	Row4	Flash time(ms)
NR	NR	600
NR	R	300
R	NR	100
R	R	80

B:

Row1	Row2	MODE	PULSE RATE	M/B
R	NR	TONE	--	--
R	R	TONE	--	--
NR	NR	PULSE	20PPS	40:60
NR	R	PULSE	20PPS	33:66
UR	NR	PULSE	10PPS	40:60
UR	R	PULSE	10PPS	33:66

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C: Tone function

Col1	Tone Duration	Inter-Tone Pause
NR	98ms	98ms
R	83ms	83ms

D: Key type select

Col2	*or */T select
NR	*
R	*/T

Note: NR: no resistance

R: A resistance connect to VSS (820kΩ typically)

UR: A resistance connect to VDD

ABSOLUTE MAXIMUM RATINGS

(Tamb=25°C, All voltage referenced to VSS, unless otherwise specified)

Characteristic	Symbol	Value	Unit
Power Supply Voltage	VDD	6.0	V
Input Voltage	VIN	-0.3~VDD+0.3	V
Power Dissipation	PD	500	mW
Operating Temperature	Topr	-25~+70	°C
Storage Temperature	Tstg	-55~+150	°C

ELECTRICAL CHARACTERISTICS

(Tamb=25°C, VDD=2.5V, fosc=3.579545MHz, unless otherwise specified)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
DC Characteristics						
Operating Voltage	VDD	Tone	2.5	--	5.5	V
		Pulse	2.0	--	5.5	
		Memory retention	1.0		5.5	
Operating Current	IOP	Tone	--	0.6	2	mA
		Pulse	--	0.2	0.5	
Standby Current	Is	ON-HOOK, No keypad entry	--	0.1	1	µA
Memory Retention Current	Imr	ON-HOOK, VDD=1.0V	--	0.1	0.2	µA
Control Pin Input Low Voltage	Vil	--	VSS		0.3VDD	V
Control Pin Input High Voltage	Vih	--	0.7VDD		VDD	
XMUTE Pin Leakage Current	Imth	V _{XMUTE} =6.0V	--	--	1	µA
XMUTE Pin Sink Current	Imtl	V _{XMUTE} =0.5V	0.2	0.5	--	mA
HKS Pin Input Current	Ihks	V _{HKS} =2.5V	--	--	0.1	µA
Keyboard Drive Current	Ikbd	Vn=0V (note1)	4	10	30	µA
Scanning Pin Sink Current	Ikbs	Vn=2.5 (note1)	200	400	800	
Key-in Debounce Time	tDB	--	--	20	--	ms

(to be continued)

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(continued)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
HFI pin input resistor	R _{hfi}	V _D =2.5	--	200	--	kΩ
HFO pin drive current	I _{hdoh}	V _{hfo} =2.0V	0.5	--	--	mA
HFO pin sink current	I _{hdol}	V _{hfo} =2.5V	0.5	--	--	mA
Pulse Mode						
Pulse Output Pin Leakage Current	I _{poh}	V _p =2.5V	0.1	--	--	μA
Pulse Output Pin Sink Current	I _{pol}	V _p =0.5V	0.5	--	--	mA
Pulse Rate	f _{pr}		--	10	--	pps
			--	20	--	
Make/Break Ratio	t _M : t _B		--	40:60	--	%
			--	33:66	--	
Pre-digit Pause	t _{PDP}	M/B ratio=40:60	--	40	--	ms
		M/B ratio=33:66	--	33	--	
Inter-digit Pause	t _{IDP}	Pulse rate=10pps	--	800	--	ms
		Pulse rate=20pps	--	500	--	
Tone Mode						
Tone Output Pin	DC Level	V _{dc}	V _D =2.0V~5.5V	0.5V _D	--	0.7V _D
	Sink Current	I _{tl}	V _d =0.5V	0.2	--	--
	AC level	V _d	Row group, R _L =10kΩ	130	155	170
	Load Resistor	R _l	Dist.≤ -23dB	10	--	--
DTMF Signal	Pre-emphasis	twist	V _D =2.0~5.5 V, Column-Row group	1	2	3
	Distortion(note 2)	Dist.	R _L =10kΩ	--	-30	-23
Minimum tone duration Time	t _{TD}	Auto redial	--	98/83	--	ms
Minimum Intertone Pause Time	t _{TP}	Auto redial	--	98/83	--	ms

Note: 1. V_n: Input voltage of any keyboard scanning pin (Row group, Column group)

2. Distortion (dB) = $20\log\{[V_1^2+V_2^2+V_3^2+\dots V_n^2]^{1/2}\}/[(V_L^2+V_H^2)^{1/2}]\}$

V_L, V_H: Row group and Column group signal , V₁, V₂..., V_n: Harmonic signal (BW = 300Hz~3500Hz)

ACTUAL FREQUENCY OUTPUT (fosc=3.579545MHz)

Keyboard Scanning Pin	Standard(Hz)	Output	Deviation(%)
R1	f1	697	+0.28
R2	f2	770	-0.52
R3	f3	852	-0.47
R4	f4	941	+0.74
C1	f5	1209	+0.57
C2	f6	1336	-0.30
C3	f7	1477	-0.34

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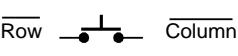
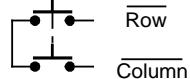
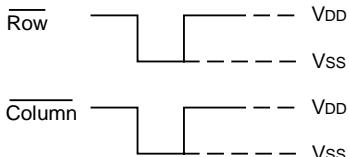
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PIN DESCRIPTION

Pin No.		Pin Name	Description
SC91710A	SC91710B		
4	4	$\overline{C1}$	*Provides keyboard scanning. * HKS pin is LOW, the column group stays in "HIGH" state and row group stays in "LOW" state.
1	1	$\overline{C2}$	*The keypad is compatible with the standard dual contact matrix keyboard (as figure1b), the inexpensive single contact keyboard (as figure 1a), and electronic input (as figure 1c).
2	2	$\overline{C3}$	*When \overline{HKS} is "LOW", a valid key entry is defined by related Row & Column connection or by electronic input (as shown in figure 1c).
3	3	$\overline{C4}$	*Activation of two or more keys will result in no response, except for single key. *To avoid keyboard-bouncing error, this chip provides built-in debounce circuit. (The debounce time = 20ms)
14	16	$\overline{R1}$	 Figure1a: Single contact form keyboard configuration
15	17	$\overline{R2}$	 Figure1b: Dual contact form keyboard configuration
16	18	$\overline{R3}$	 Figure1c: Electronic signal input keyboard configuration
13	15	$\overline{R4}$	
5	5	OSCI	*Oscillator input & output pins. *The 3.579545MHz oscillator is formed by a built-in inverter inside of this chip and by connecting a 3.579545MHz crystal or a ceramic resonator across the OSCI and OSCO pins. (built-in feedback resistor and capacitor)
6	6	OSCO	*When \overline{HKS} is "LOW", a valid key-in may turn on this oscillator and generates a 3.579545 MHz clock.

(to be continued)

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SC91710A/B

(continued)

Pin No.		Pin Name	Description
SC91710 A	SC91710B		
7	7	XMUTE	*Mute output pins. *NMOS open drain output structure. *The output is in "LOW" state during dialing sequence (both Pulse and Tone mode) otherwise this pin is "high-impedance". *Long (continue) Mute.
8	8	VSS	*Negative power supply pin.
9	11	VDD	*Positive power supply pin.
10	12	HKS	*Hook switch input pin. *When the handset is in ON-HOOK state, this pin must be pulled "high" in order to disable the dialing operation and decrease the power consumption. *When in OFF-HOOK state, the HKS pin must be pulled "low" state for all function operation.
11	13	PO	*Pulse output signal pin. *NMOS open drain output structure. *The output is "LOW" during pulse dialing and Flash operation, otherwise this output is "floating".
12	14	TONE	*Dual Tone Multi-frequency output pin. *In TONE mode, when an entry of digit key (include *, # key), this pin will send out a corresponding DTMF signal. *The TONE pin provides minimum tone duration and minimum intertone pause time to support rapid key-in. If key-in time is less than 100ms, DTMF signal will last for 100ms; otherwise the tone duration will last as long as the key is pressed.
	9	HFI	* Handfree input control pin. * Toggle input structure, falling edge trigger. * It is used to enable and disable Handfree function. * With waveshaped by a built-in Schmit trigger, the bounce of input can be eliminated by external R, C debounce circuit. * A built-in pull down resistor is 200k typical.
	10	HFO	* Handfree output control pin. * Inverter output structure (normally 'low', active 'high'). * When a HFI pin is active, Handfree function will be enabled (HFO=1) or disable (HFO=0). * When the Handfree function is enable (HFO=1), after OFF-HOOK action, it can reset Handfree function and HFO pin return to 'low' state.

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KEYBOARD OPERATION

Symbol definitions:

- a) \uparrow : OFF-HOOK or enable Hand Free function.
- b) \downarrow : ON-HOOK or disable Hand Free function.
- c) : Input level from low to high.
- d) : Input level from high to low.
- e) D1~Dn : Digit key; 1, 2, 3, 4, 5, 6, 7, 8, 9, 0, *, #, (C1~Cn is same as D1~Dn).
- f) Dp1~Dpn : Pulse digit; 1, 2, 3, 4, 5, 6, 7, 8, 9, 0, (Cp1~Cpn is same as Dp1~Dpn).
- g) Dt1~Dtn : Tone digit; 1, 2, 3, 4, 5, 6, 7, 8, 9, 0, *, #, (Ct1~Ctn is same as Dt1~Dtn).
- h) t_F : Flash time.
- i) t_P : Pause time.
- j) t_{PT} : Pulse to Tone wait time.
- k) t_{FP} : Pause time for flash.
- l) t_{RP} : Pause time for redial.
- m) LNB : Last number redial buffer.

A) Normal Dialing

1. Digit Dialing

- Procedure : \uparrow D1, D2..., Dn \downarrow
- Dial out : Dt1, Dt2..., Dtn (in Tone mode)
- Dial out : Dp1, Dp2,..., Dpn (in Pulse mode)
- LNB : D1, D2..., Dn

2. Dialing with flash key

- Procedure : \uparrow F, D1, D2..., Dn \downarrow
- Dial out : t_F , t_{FP} , Dt1, Dt2..., Dtn (in Tone mode)
- Dial out : t_F , t_{FP} , Dp1, Dp2, ..., Dpn (in Pulse mode)
- LNB : D1, D2..., Dn

3. Dialing with P→T key

- Procedure : \uparrow D1, D2 ..., P→T, ..., Dn \downarrow
- Dial out : Dp1, Dp2, ..., t_{PT} , ..., Dpn (in Pulse mode)
- LNB : D1, D2 ..., P→T, ..., Dn

Note: If key in digit over maximum digit stored in LNB, then RD is inhibit even after on/off hook.



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B) Mixed dialing

Procedure	:	$\uparrow D_1, D_2 \dots, P \rightarrow T, D_9, D_{10} \dots, D_n \downarrow$
Dial out	:	$D_{p1}, D_{p2}, \dots, t_{PT}, D_{t9}, D_{t10} \dots, D_{tn}$
LNB	:	$D_1, D_2 \dots, P \rightarrow T, D_9, D_{10} \dots, D_n$

C) Redial

LNB	:	$D_1, D_2 \dots, D_n$
Procedure	:	$\uparrow RD \downarrow$
Dial out	:	$t_{RP}, D_{t1}, D_{t2} \dots, D_{tn}$ (in Tone mode)
Dial out	:	$t_{RP}, D_{p1}, D_{p2}, \dots, D_{pn}$ (in Pulse mode)

Note: If key in digit over maximum digit stored in LNB, then RD is inhibit.

D) Pause Function

Procedure	:	$\uparrow D_1, D_2 \dots, D_n, P, C_1 \dots, C_n \downarrow$
Dial out	:	$D_{t1}, D_{t2}, \dots, D_{tn}, t_P, C_{t1}, C_{t2} \dots, C_{tn}$ (in Tone mode)
Dial out	:	$D_{p1}, D_{p2}, \dots, D_{pn}, t_P, C_{p1}, C_{p2} \dots, C_{pn}$ (in Pulse mode)
LNB	:	$D_1, D_2 \dots, D_n, P, C_1, C_2 \dots, C_n$

E) Flash Function

1. Reset

Procedure	:	$\uparrow D_1, D_2 \dots, D_n, F, C_1 \dots, C_n \downarrow$
Dial out	:	$D_{t1}, D_{t2}, \dots, D_{tn}, t_F, t_{FP}, C_{t1}, C_{t2} \dots, C_{tn}$ (in Tone mode)
Dial out	:	$D_{p1}, D_{p2}, \dots, D_{pn}, t_F, t_{FP}, C_{p1}, C_{p2} \dots, C_{pn}$ (in Pulse mode)
LNB	:	$C_1, C_2 \dots, C_n$

Handfree Function operation:

A) To execute Handfree function: When HFO = 'low', HFI pin is active, the Handfree function will be enabled (HFO = 'high')

B) Reset Handfree function:

a. OFF-HOOK action.

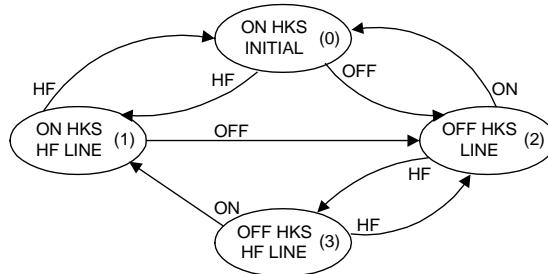
b. When HFO = 'high', a HFI pin is active again, the Handfree function will be reset (HFO='low').



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Operating flow chart of Handfree



Note: ON: ON HKS; OFF: OFF HKS; HF: Pressed HF key

STATE NO.	PO	XMUTE	HFO
(0) INITIAL STATE	F	F	0
(1) ON HKS HF LINE	F	F	1
(2) OFF HKS LINE	F	F	0
(3) OFF HKS HF LINE	F	F	1

* F: Floating
(Hi-impedance)

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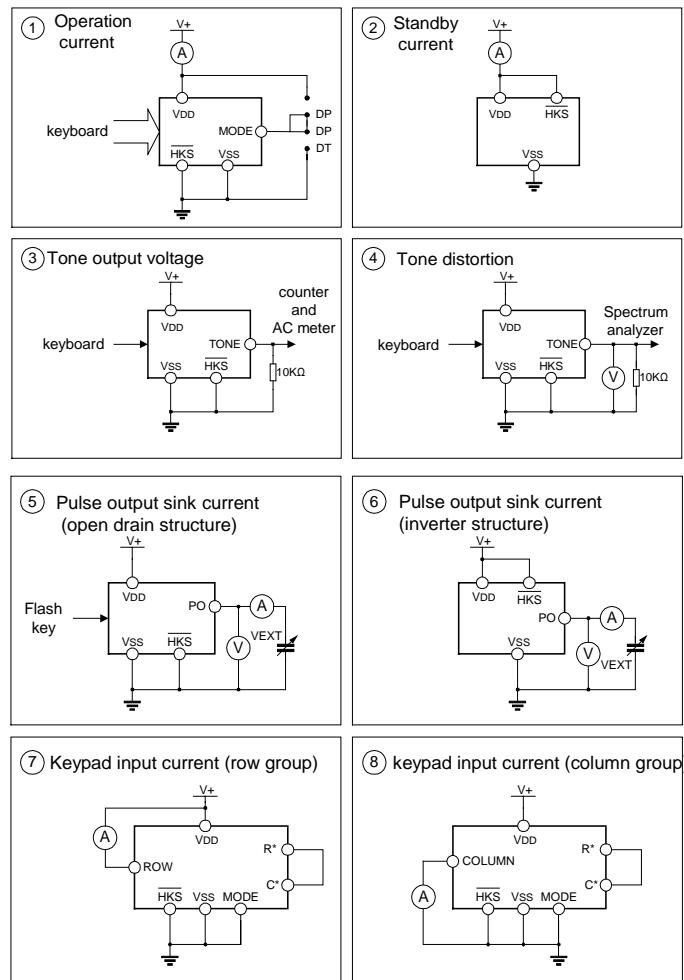
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TEST CIRCUIT



Note: 1. Dist. (dB)= $20\log\{[V_1^2+V_2^2+V_3^2+\dots V_n^2]^{1/2}\}/[(V_L^2+V_H^2)^{1/2}]\}$

a. $V_1\dots V_n$ are extraneous frequencies (ie, inter modulation and harmonic), components in the 500Hz to 3400Hz band.

b. V_L, V_H are the individual frequency components of DTMF signal.

c. Whether keyboard is pushed refer to the TONE mode time diagram.

2. Sink current $I_{sink}=I/(1-\text{Duty Cycle})$, I is the net DC current measured from ampere meter.

3. R^* , C^* mean other column and row.

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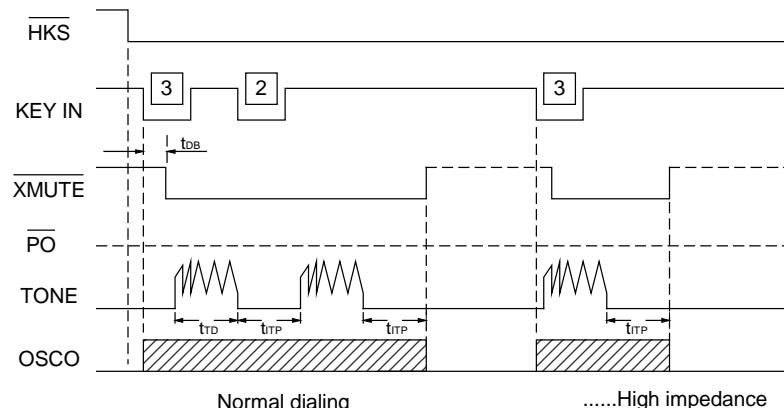
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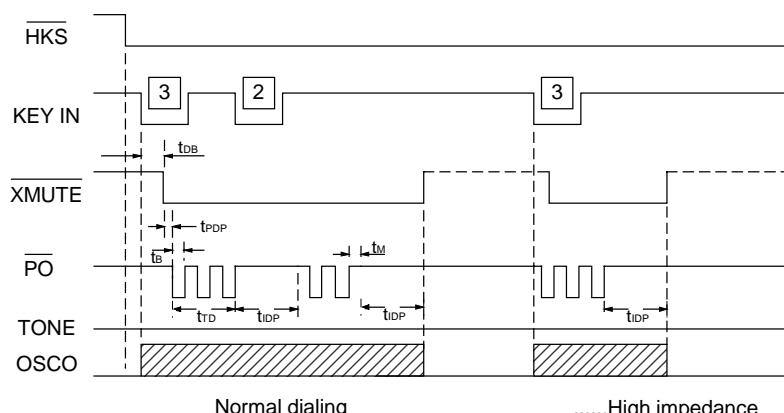
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TIMING DIAGRAMS



Tone Mode Timming Diagram



Pulse Mode Timming Diagram

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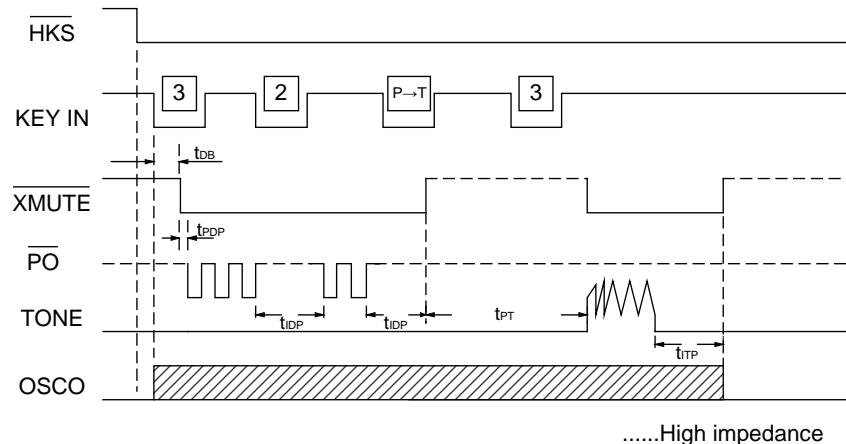
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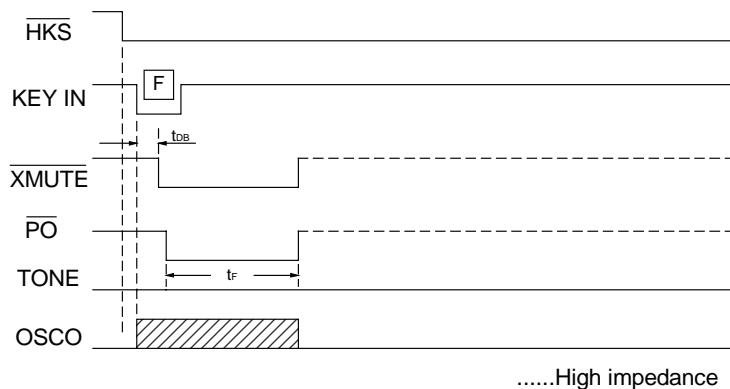
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TIMING DIAGRAMS (continued)



Timing Waveform for mixed dialing Operation
(by P→T key entry)



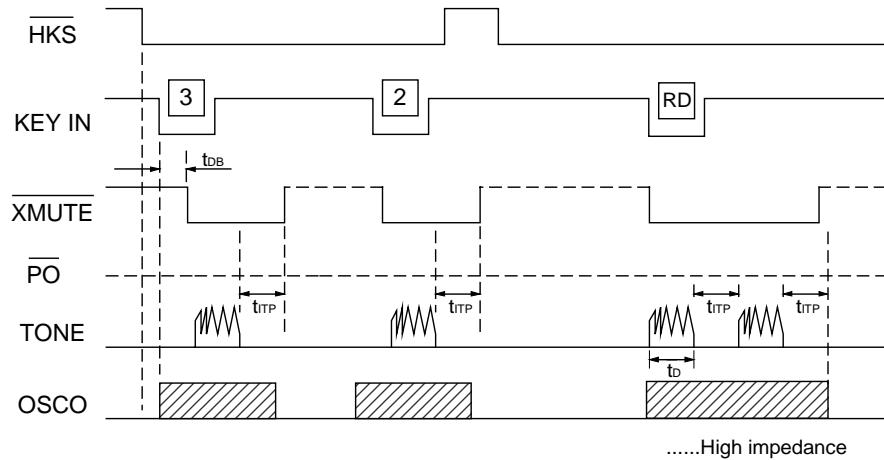
Flash key operating timing



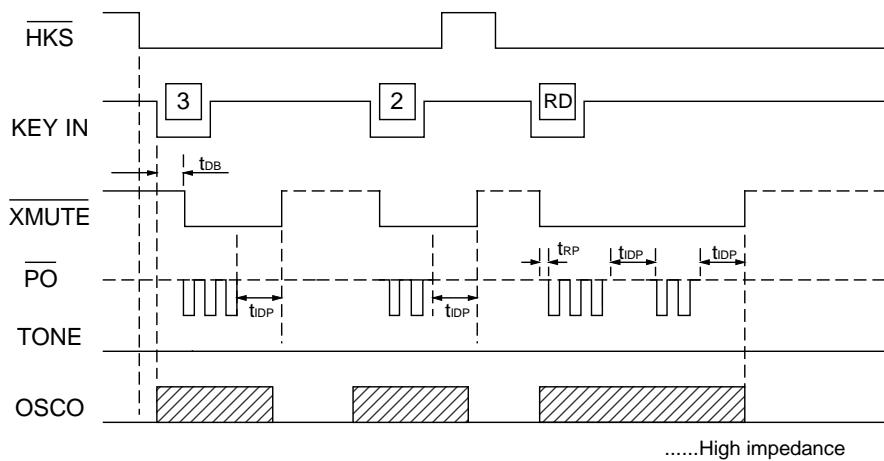
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TIMING DIAGRAMS(continued)



Tone Mode Redial Timming Diagram



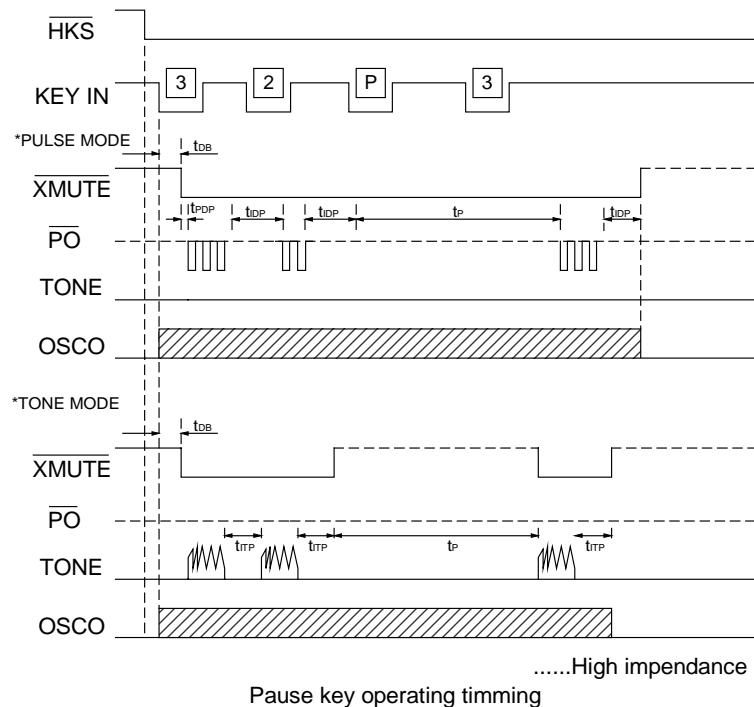
Pulse Mode Redial Timming Diagram



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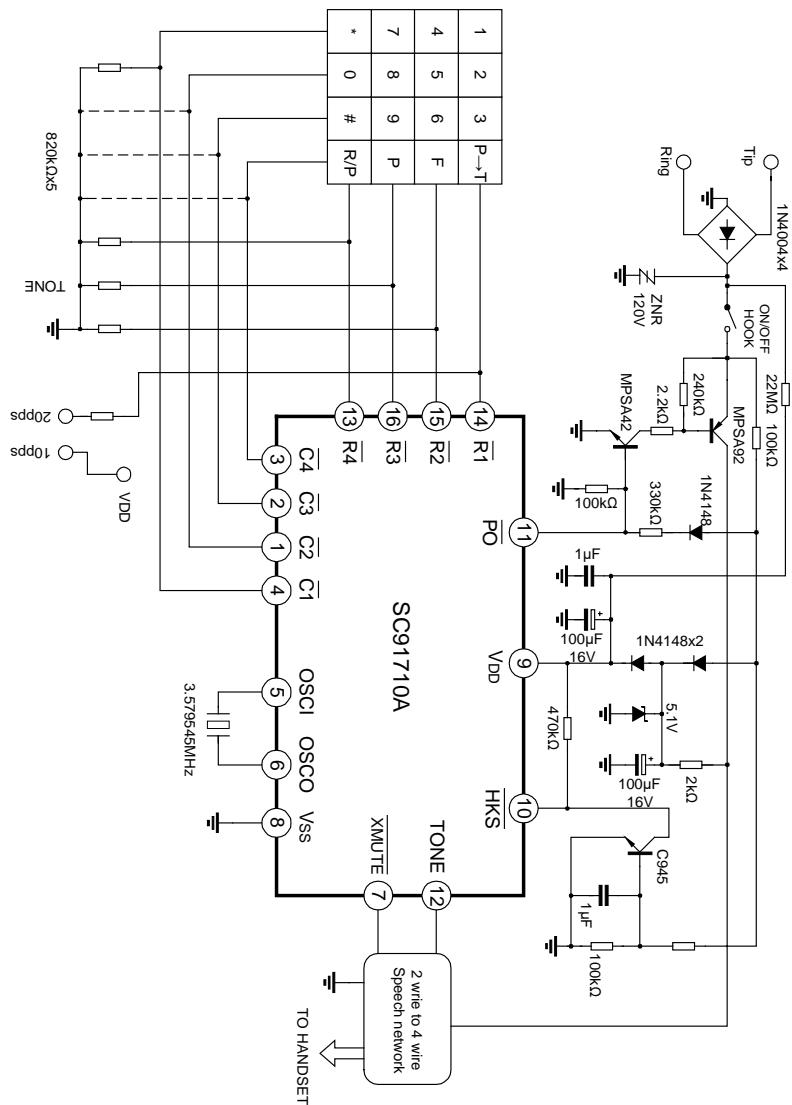




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TYPICAL APPLICATION CIRCUIT



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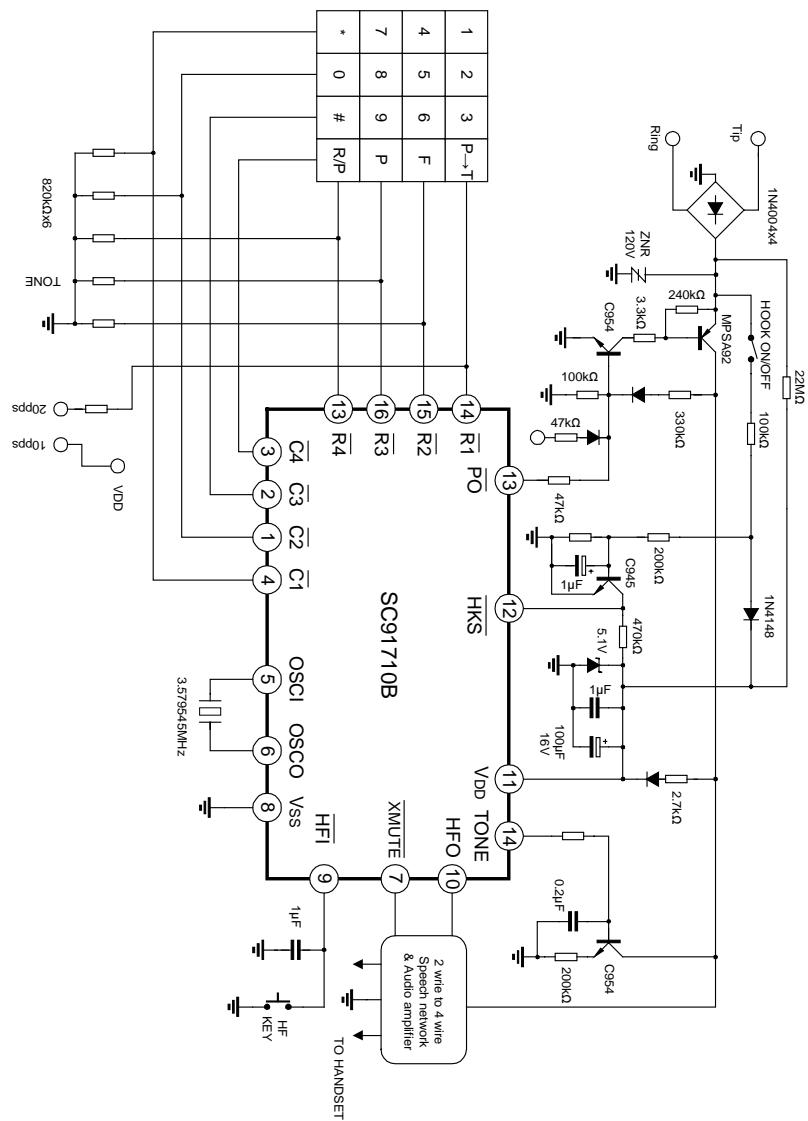
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TYPICAL APPLICATION CIRCUIT



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CHIP TOPOGRAPHY



Size: 1.45 x 1.54 mm²

PAD COORDINATES (Unit: μm)

No.	Symbol	X	Y	No.	Symbol	X	Y
1	P1	-542.6	-238.0	10	P10	562.4	88.5
2	P2	-542.6	-468.1	11	P11	562.4	252.4
3	P3	-542.6	-602.5	12	P12	562.4	445.8
4	P4	-315.0	-602.5	13	P13	562.4	603.8
5	P5	-134.8	-602.5	14	P14	148.6	603.8
6	P6	85.5	-602.5	15	P15	-22.4	603.8
7	P7	562.4	-439.1	16	P16	-251.0	603.8
8	P8	562.4	-277.6	17	P17	-542.6	124.7
9	P9	562.4	-93.6	18	P18	-542.6	-102.9

Note: The original point of the coordinate is the die center.

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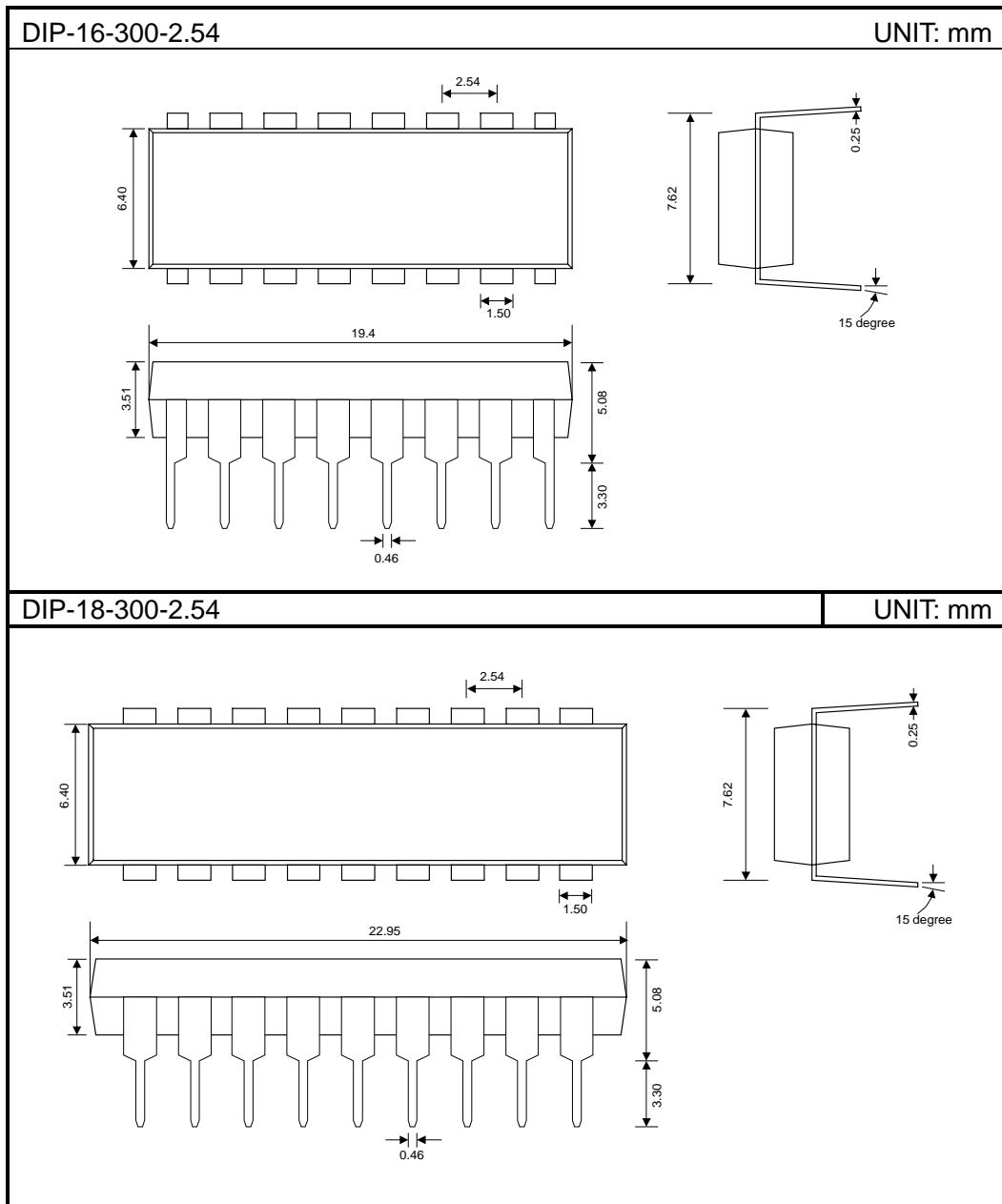
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PACKAGE OUTLINE



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